



Attorney Docket No.: 114183-7
Ref. No.: P98-0040US2
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Daniel J. Woodruff et al.

Application No.: 10/084,962

Confirmation No.: 2206

Filed: February 27, 2002

Art Unit: 1742

For: ELECTROPLATING APPARATUS WITH
SEGMENTED ELECTRODE ARRAY

Examiner: Lois L. Zheng

DECLARATION OF DANIEL J. WOODRUFF AND KYLE M. HANSON
UNDER 37 C.F.R. § 1.131

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

We, Daniel J. Woodruff and Kyle M. Hanson, hereby declare and say that:

1. We are employed by the assignee of the above-identified application, Semitool, Inc. ("Semitool") and have been named as joint inventors of the subject matter described and claimed in U.S. Patent Application No. 10/084,962, filed February 27, 2002, which is a continuation of U.S. Patent Application No. 09/113,418, filed July 10, 1998, and now U.S. Patent No. 6,497,801. This declaration is submitted to show conception and actual reduction to practice of the claimed invention in this country prior to February 12, 1998, and thus before the earliest filing date to which U.S. Patent No. 6,391,166 B1 claims priority.

BEST AVAILABLE COPY

2. Prior to February 12, 1998, we conceived and reduced to practice the invention presented in the claims of the above-captioned patent application. Our conception and actual reduction to practice of the claimed invention are each corroborated by (a) Semitool Invention Disclosure – 0006 for the concentric electrode array reactor (Exhibit A), (b) Semitool Fabrication Drawings for the concentric electrode array (Exhibit B), (c) Semitool Invention Disclosure – 0005 for the concentric electrode array reactor (Exhibit C), (d) Semitool Work Requests for building the components of the concentric electrode array (Exhibit D); and (e) Semitool Reactor Drawings for a preexisting reactor developed by Semitool (Exhibit E).

3. We prepared and signed Semitool Invention Disclosure – 0006 well before February 12, 1998, and this document was also witnessed and understood by two colleagues at Semitool before February 12, 1998. Semitool Invention Disclosure – 0006 lists dates of conception and written description before February 12, 1998.

4. The Semitool Fabrication Drawings include Semitool Drawing Nos. ATG0233-ATG0238, which were also prepared before February 12, 1998. Semitool Drawing No. ATG0233, more specifically, includes isometric, cross-sectional and exploded views that correspond to Figures 2-5 of the present application.

5. We also prepared and signed Semitool Invention Disclosure – 0005 before February 12, 1998, and this document was also witnessed by colleagues at Semitool before February 12, 1998. Semitool Invention Disclosure – 0005 lists the dates of conception and written description before February 12, 1998.

6. As shown in Semitool Invention Disclosure – 0006, the Semitool Fabrication Drawings, and Semitool Invention Disclosure – 0005, we conceived of a system for electroplating a layer of material on a semiconductor wafer. In one embodiment, such as set forth in claim 17, the system includes an electrochemical cell comprising a primary anode, a cathode contact, and a chamber in which the primary anode and the cathode are

disposed (Exhibit A, p. 1). We further conceived of one secondary anode for providing a variable current to the semiconductor wafer (Exhibits A-C), and using an electrolytic solution disposed within the electrochemical cell (Exhibit A, p. 1). We also conceived of applying different anode potentials to individual electrodes (Exhibit A, p. 2), and independently controlling the electrical potential to each anode to dynamically modify the anode configuration (Exhibit C, p. 1). We accordingly conceived of a power source capable of providing varying levels of voltage to a primary anode and a secondary anode.

7. We conceived of still further aspects of systems for electroplating a layer of material on a semiconductor wafer. For example, we conceived that the anodes can have a ring-shape (Exhibits A-C), the secondary anode can include a first secondary anode and a second secondary anode (Exhibits A-C), and/or the secondary anodes can comprise first and second concentric rings (Exhibits A and B). We further conceived that the wafer can act as a cathode to receive an electroplating film (Exhibit A, p. 1). We also conceived that a variable current or a variable voltage can be applied to the anodes (Exhibits A and C).

8. We also conceived of an anode system for performing an electroplating operation. In one embodiment, such as set forth in claim 32, such an anode system includes a plurality of anodes for performing an electroplating operation on a part (Exhibits A-C). We further conceived that the anodes are insulatively coupled together on a dielectric mount (Exhibit B, Semitool Drawing Nos. ATG0233 and ATG0234), and operating the anodes to provide a variable current to the plurality of anodes by varying the voltage levels (Exhibit C). We further conceived of a plurality of leads respectively coupled to the anodes such that the leads have the capability of providing independent electrical currents from a power source to respective anodes. More specifically, the anode mount illustrated in Semitool Drawing Nos. ATG0233 and ATG0234 (Exhibit B) include mounting holes through which individual leads can independently provide electrical currents to individual anodes.

9. After conceiving this invention, we reduced the invention to practice by constructing a prototype of the concentric electrode array according to Semitool Drawing Nos. ATG0233 to ATG0238 (Exhibit B) prior to February 12, 1998. More specifically, Semitool Work Requests 00474-00478 (Exhibit C) were submitted to Semitool's shop for fabricating the individual components shown in Semitool Drawing Nos. ATG0234 to ATG0238 well before February 12, 1998. Additionally, we indicated that the date needed for receiving the components of the concentric electrode array from the shop was also well before February 12, 1998. We proceeded to assemble the components illustrated in Semitool Drawing Nos. ATG0234 to ATG0238 and the concentric electrode assembly shown in Semitool Drawing No. ATG0233 was fabricated and assembled well before February 12, 1998.

10. Semitool had also created reactor vessels before February 12, 1998. For example, sheets 1-3 of Semitool Drawing Nos. 100T0041 (Exhibit E) were created well before February 12, 1998. No inventive effort was required to assemble the concentric electrode assembly shown in Semitool Drawing No. ATG0233 (Exhibit B) with the vessel illustrated in Semitool Drawing No. 100T0041 (Exhibit E) as shown in Semitool Invention Disclosure – 0006 (Exhibit A, p. 1).

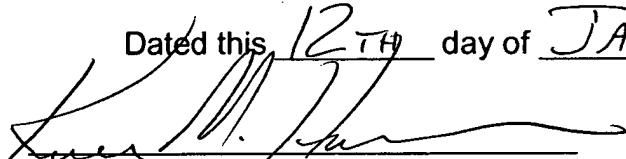
11. We previously submitted a declaration under 37 C.F.R. § 1.131 that demonstrated we further conceived and reduced to practice the subject matter of the claims in this application before April 21, 1998, which is the earliest filing date claimed by U.S. Patent No. 6,261,433 issued to Landau (Exhibit F). As stated in our previous declaration under 37 C.F.R. § 1.131 directed to U.S. Patent No. 6,261,433, the electrode array was built, installed in a plating reactor as described in the present application, and successfully tested before April 21, 1998.

12. The dates contained on each of the Exhibits have been removed, but all of the dates in Exhibits A-E are before February 12, 1998, and thus corroborate the

conception and actual reduction to practice of the subject matter disclosed and claimed in the present application.

13. We further declare that all statements herein made of our own knowledge are true, and that all statements made on information or belief are believed to be true; and further, that the statements are made with the knowledge that the making of willful or false statements or the like is punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and may jeopardize the validity of any patent issuing from this patent application.

Dated this 12TH day of JANUARY, 2006.



Kyle M. Hanson



Daniel J. Woodruff

EXHIBIT A

INVENTION DISCLOSURE

SEMITOOL, INC.

D. 0006

- Note:
1. Use Ink or Type Only
 2. Do not erase errors. Line through any errors, initial and date.
 3. Describe invention with drawings, sketches, etc. and a written explanation. Drawings may be below or attached.
If attached, the inventor(s) and witnesses must sign and date each sheet.
 4. Describe the advantages of this invention compared to the current approach, if any.
 5. Inventor(s) and two (2) witnesses must sign and date each sheet.
 6. Send original signed documents to the Intellectual Property Department. Retain a personal copy.

Inventor(s) Name and Social Security Number

Daniel J. Woodruff
Kyle M. Hanson

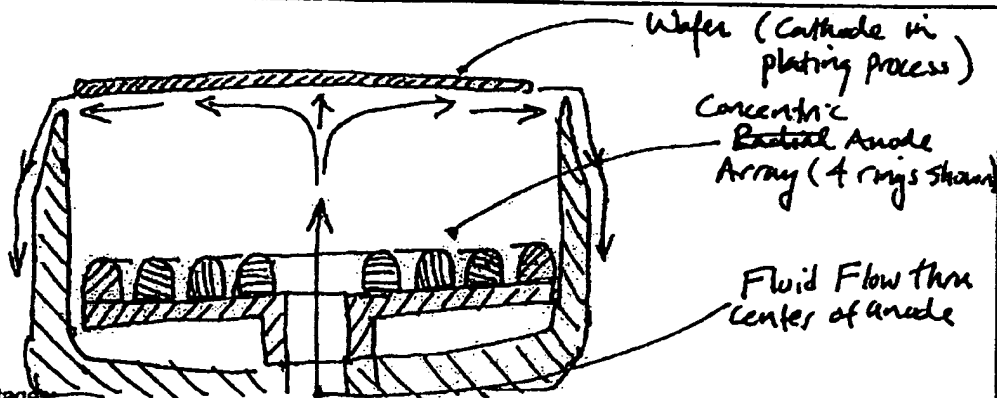
Title of Invention:

TOOL: Plating

Concentric Anode Array with Centered Fluid Flow

Invention:

Sketch



Explanation and Advantages:

Plating fluid is pumped through the center of the anode array and impinges on the wafer surface. The plating rate on the wafer surface will vary radially ~~across the~~ due to the effect of the impinging fluid on the hydrodynamic boundary layer. This radial effect can be compensated for ~~in the~~ by operating the anode rings at different electrical potentials.
(continued on attached sheet)

Signature(s) of Inventor(s):

Date:

Date of Conception:

Date of First Sketch/Drawing:

Witnessed and Understood By:

Date:

Date of Written Description:

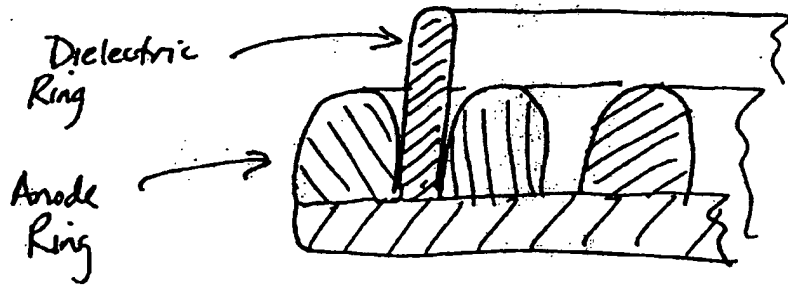
Working Model Prepared?

Yes/No

Date:

Explanation and Advantages (Cont.)

In addition to affecting plating uniformity by using different anode potentials it would also be possible to affect uniformity with dielectric (insulating) material placed between the anode ring (see sketch



The geometry of the dielectric material could be modified to provide the desired effect on plating. Tall geometries would tend to limit interaction of adjacent anodes (and perhaps collimate current flow to the wafer) while shorter or perforated geometries would tend to increase anode interaction. Similar effects may also be possible by positioning the anode rings at varying distances from the water surface.

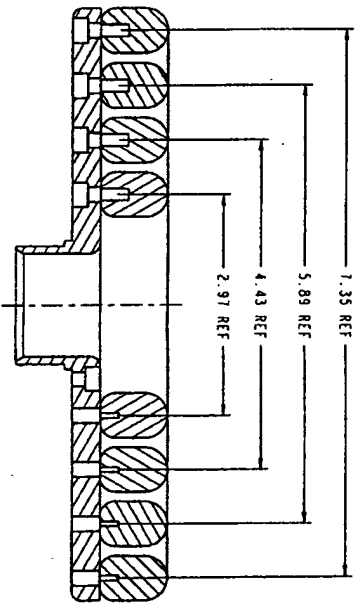
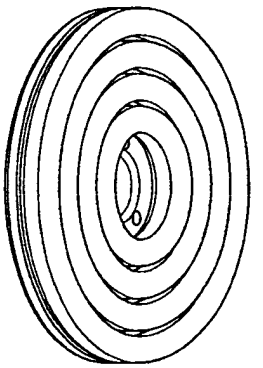
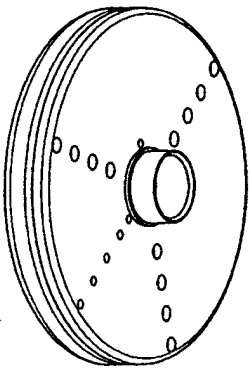
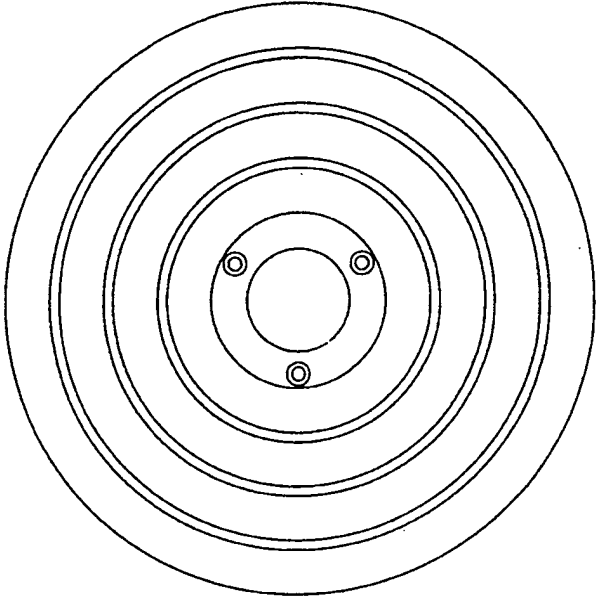
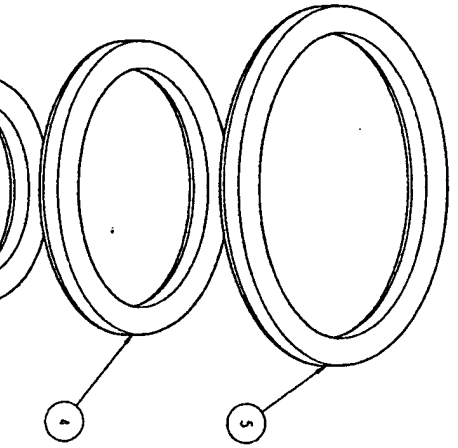
The advantages to this design are:

- 1) No diffuser is required between the anode and wafer. Fluid flow rate and current distribution can be controlled independent of one another in the proposed design, but can't in the existing system which uses a diffuser constructed of dielectric material. Having these variable independently controllable makes it easier to optimize the plating process.
- 2) Air bubbles introduced into the plating chamber by the incoming fluid flow are simply flushed passed the wafer surface and won't interfere with the plating process. With the existing system utilizing a diffuser these bubbles can attach to the diffuser surface and adversely impact diffuser performance.
- 3) Fluid flow through the center of the anode ensures the wafer surface will be wetted from the center out. This will prevent air being trapped at the center of the wafer when it first contacts the fluid surface.

3

David J. Waduff
Kris Han

EXHIBIT B



ITEM	QTY	PART NUMBER	DESCRIPTION
1	1	ATG0234	MOUNT, ANODE, RADIAL ARRAY
2	1	ATG0235	ANODE, RING, 2.97 DIA.
3	1	ATG0236	ANODE, RING, 4.43 DIA.
4	1	ATG0237	ANODE, RING, 5.89 DIA.
5	1	ATG0238	ANODE, RING, 7.35 DIA.

1.35 REF
 5.89 REF
 4.43 REF
 2.97 REF

SEMITOOL PROPRIETARY

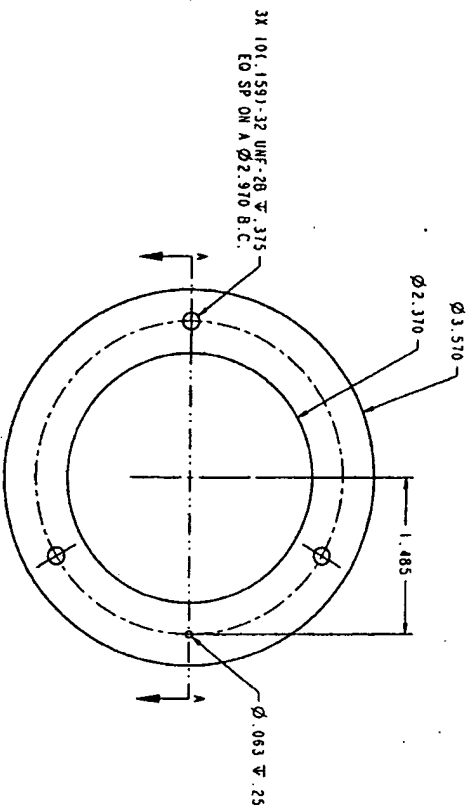
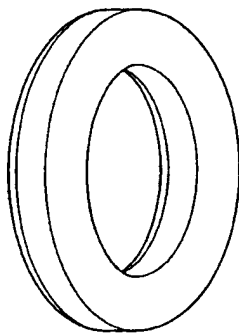
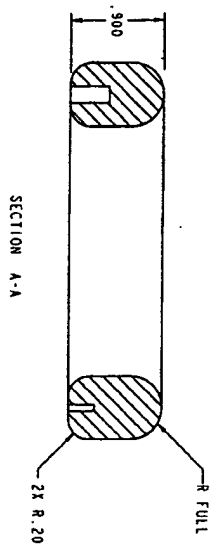
DATE	REV	DESCRIPTION	BY	DATE
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SEMITOL
 ANODE ASSEMBLY
 VARIABLE ARRAY

ATG0233

ARTICLE	REF.	SHEET	1/10
FIGURE			
ORDER NO.	AT60234		
<h1>SEMITOOL™</h1> <p>THE CALIBRELL, INC.</p> <p>MOUNT, ANODE, VARIABLE ARRAY</p>			
FIGURE NO.			
ORDER NO.	AT60234		
DATE	1	Q	1

REV	DATE	DESCRIPTION	BY	DATE



SEMITOOL PROPRIETARY

DATE	REV	DESCRIPTION	BY	DATE

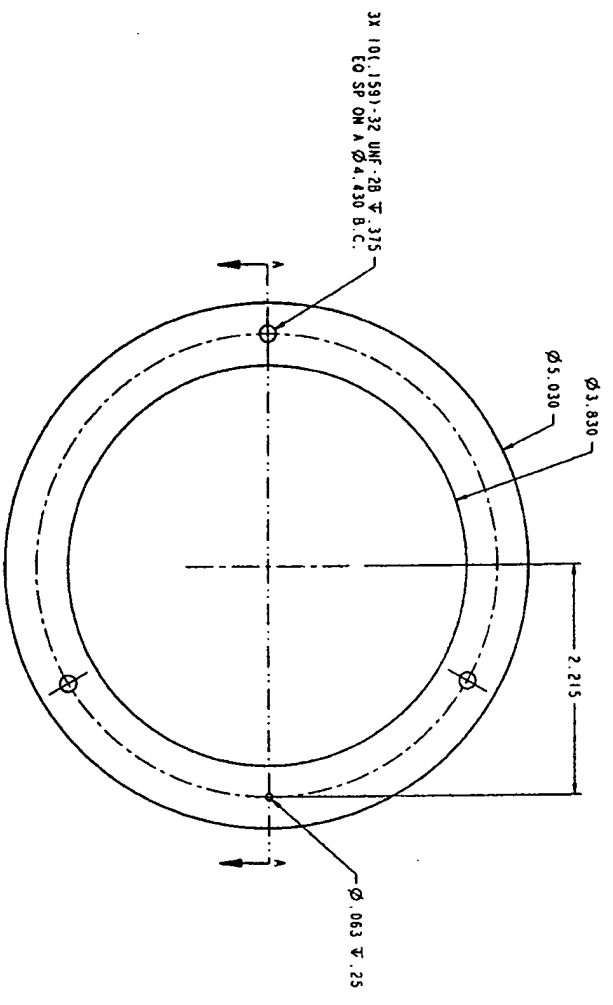
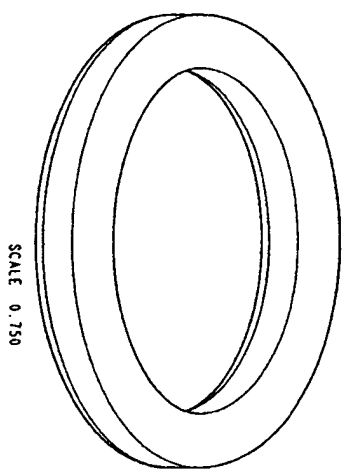
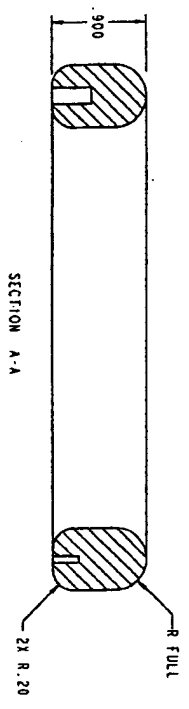
DATE	REV	DESCRIPTION	BY	DATE

TO: SEMITOOL
FROM: SEMITOOL
DATE: 01/01/00
REVISION: 01/01/00
NOTES: 01/01/00

DATE	REV	DESCRIPTION	BY	DATE

SEMITOOL
ANODE RING, 297 DIA

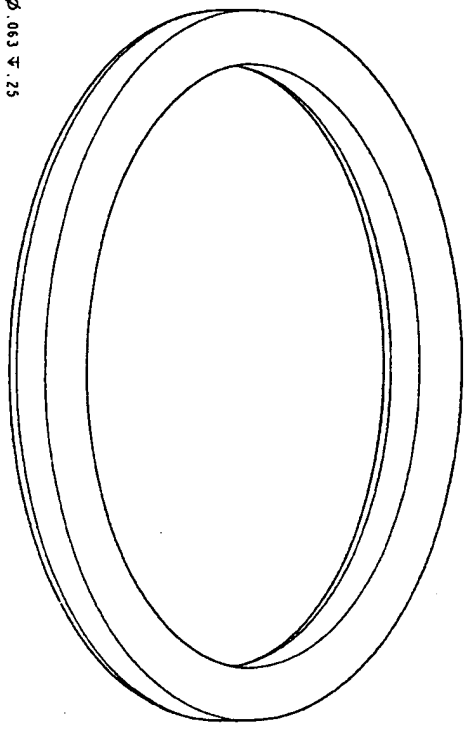
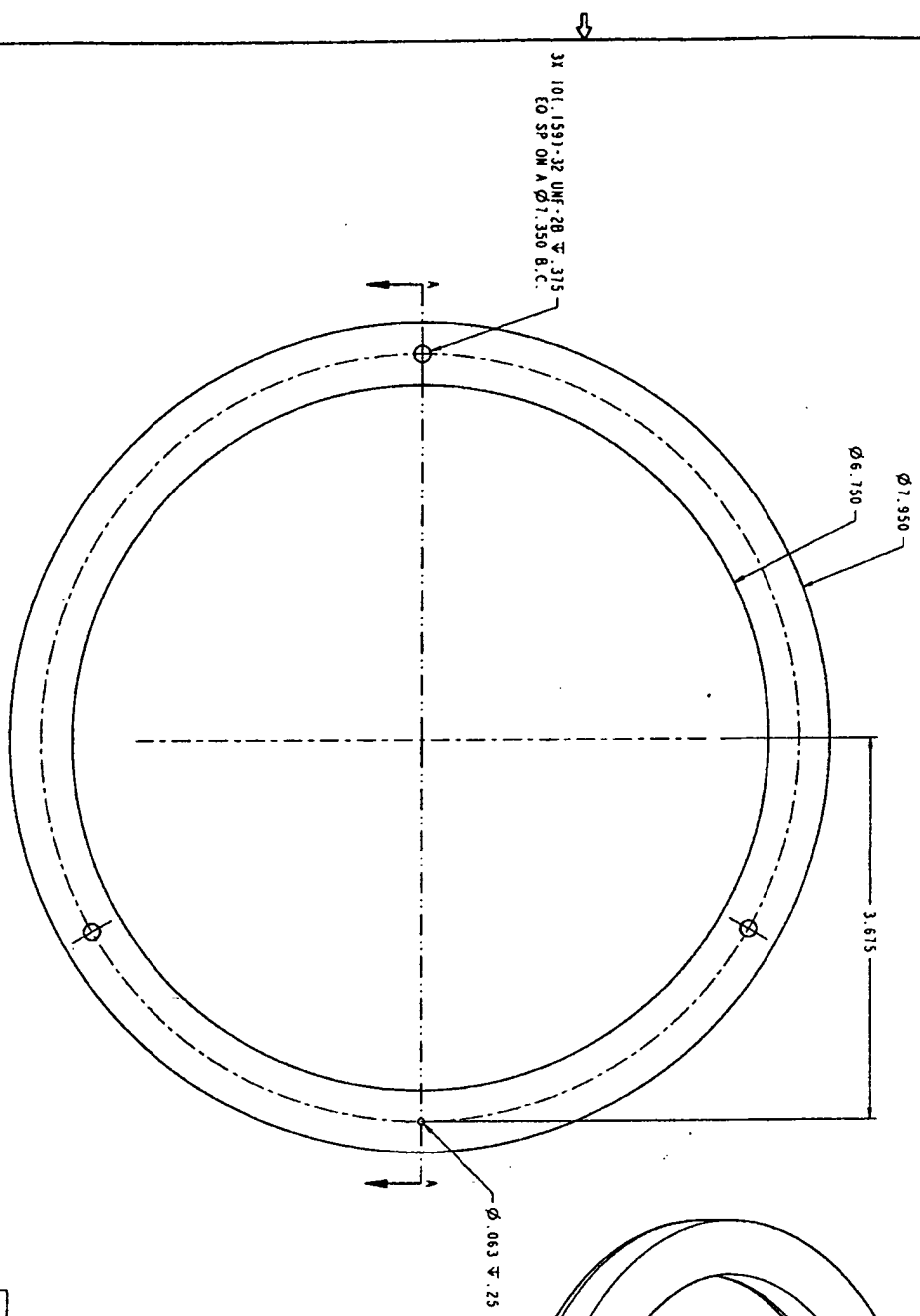
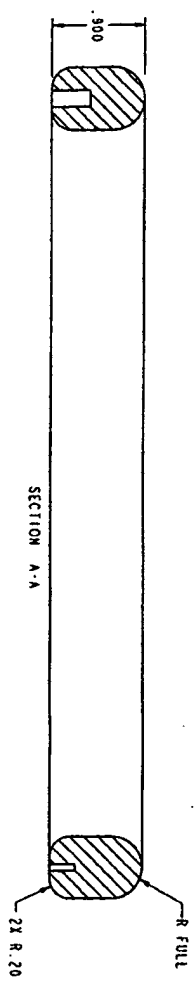
REVISIONS			
REV	DATE	DESCRIPTION	BY
1		SECTION A-A	ATG



SEMITOOL PROPRIETARY

DRAWING		COPY 15.92	
PART		A160215	
DATE		11/02/15	
ON FRANKLIN COUNTY, MASSACHUSETTS SEMITOOL, INC. 1000 ROUTE 1 WILKINSON, MASSACHUSETTS 01973 TEL: 508/548-1111 FAX: 508/548-1112 WWW.SEMITOOL.COM			
SEMITOOL ANODE RING, 4.43 DIA		ATG0236 REV 1.01	

REVISIONS			
REV	DATE	DESCRIPTION	BY



SEMITOOL PROPRIETARY

MATERIAL: COPPER 99.95		PART NO: A160238	
FINISH: -		REV: 1	
QUANTITY: 1		DATE: 0.815	
DRAWN BY: JJC		CHECKED BY: JJC	
SCALE: 0.750		PART NO: A160238	
SEMITOOL™		ANODE RING 7.35 DIA	
101.1591-32 UNF-28 ± .315		EO SP OM A Ø1.350 B.C.	

EXHIBIT C

INVENTION DISCLOSURE

D. -0005
B. 50

SEMITOOL, INC.

Note: 1. Use Ink or Type Only
2. Do not erase errors. Line through any errors, initial and date.
3. Describe invention with drawings, sketches, etc. and a written explanation. Drawings may be below or attached. If attached, the Inventor(s) and witnesses must sign and date each sheet.
4. Describe the advantages of this invention compared to the current approach, if any.
5. Inventor(s) and two (2) witnesses must sign and date each sheet.
6. Send original signed documents to the Intellectual Property Department. Retain a personal copy.

Inventor(s) Name

KYLE M. HANSON

HENRY . STEVENS

CHRIS K. HAUGAN

DANIEL J. WOODRUFF

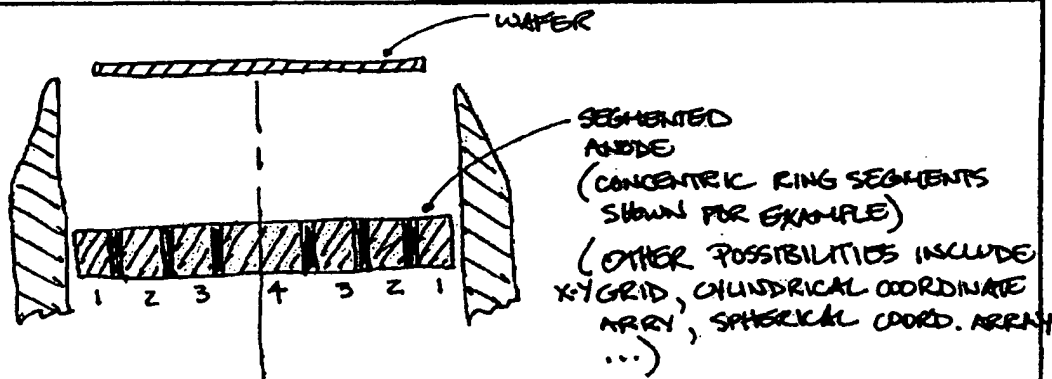
Tool or Process: ELECTROCHEMICAL DEPOSITION

Title of Invention:

ANODE CONFIGURATION DYNAMIC CONTROL

Invention:

Sketch



Explanation and Advantages:

Then the use of a segmented anode structure and independent electrical control on each of these segments (definition of voltage or current flow), the capability to dynamically modify the anode configuration is enabled. This allows for optimization of the anode and therefore reactor current flow in order to compensate for the transient

Signature(s) of Inventor(s):

Date:

Date of Conception:

Date of First Sketch/Drawing:

Chris Haugan

Henry Stevens

Daniel J. Woodruff

Witnessed and Understood By:

Date:

Date of Written Description:

Working Model Prepared?

Kyle Hanson

Chris Haugan

Henry Stevens

Daniel J. Woodruff

Yes

(No)

Date:

Explanation & Advantages (cont)

effects from the plated film growth on the wafer. As the film grows on the wafer the current distribution on the wafer will change due to the difference in the films electrical conductivity.

This capability to dynamically alter the anode configuration as the process progresses is becomes more important in the case of high resistance seed layers. In this case, the transient change in the film characteristics is made larger in magnitude as a layer of high electrical conductivity copper, for example, is deposited on a much lower conductivity layer.

The sensitivity of plating to local current density is a function of the electrochemical process at the surface. For a given potential, the current density is related to the local surface area. The potential is applied to each anode segment individually.

[Signature]

Chris Hargrave
 David W. Wadsworth
 Henry Stevens
 Kenneth
 Brown

EXHIBIT D

Work Request

00474

Approved By: DW

Date: _____

Circle One:

Jobs #:

Rework _____
 Vendor Rework _____
 Engineering 64736 _____
 Return Material _____
 Other _____

When Completed Deliver To:

Name: TRACI DELLON/DAN WUDRA

Area: AT4

Qty to Job: 1

Qty to Inv: 1

☒ Machine Shop

☐ Poly

☐ Weld

Qty Required: 1

Date Needed: _____

Item/Part #: AT4 734

Description: MOUNT ANGLE RADIAL ARRAY

Action Required: PAINT

Reason: _____

Work Request

00475

Approved By: DW

Date: _____

Circle One:

Jobs #:

Rework _____
 Vendor Rework _____
 Engineering 64736 _____
 Return Material _____
 Other _____

When Completed Deliver To:

Name: TRACI DELLON/DAN WUDRA

Area: AT4

Qty to Job: 1

Qty to Inv: 1

☒ Machine Shop

☐ Poly

☐ Weld

Qty Required: 1

Date Needed: _____

Item/Part #: AT4 735

Description: ANGLE RADIAL ARRAY

Action Required: PAINT

Reason: _____

Work Request

00476

Approved By: DW

Date: _____

Circle One:

Jobs #:

Rework

Vendor Rework

Engineering

Return Material

Other:

109734

When Completed Deliver To:

Name: TRK1 DEGRON/DAN WOODKILL

Area: AT29

Qty to Job: 1

Qty to Inv: 1

☒ Machine Shop

☐ Poly

☐ Weld

Qty Required: 1

Date Needed: _____

Item/Part #: ATL 62312

Description: AN 2, 4IN, 112 DIA

Action Required: PA PRINT

Reason: _____

Work Request

00477

Approved By: DW

Date: _____

Circle One:

Jobs #:

Rework

Vendor Rework

Engineering

Return Material

Other:

67736

When Completed Deliver To:

Name: TRK1 DEGRON/DAN WOODKILL

Area: AT21

Qty to Job: 1

Qty to Inv: 1

☒ Machine Shop

☐ Poly

☐ Weld

Qty Required: 1

Date Needed: _____

Item/Part #: ATL 6237

Description: AN 2, 4IN, 54 DIA

Action Required: PA PRINT

Reason: _____

Work Request

00478

Approved By: DAN

Date: _____

Circle One:

Jobs #:

Rework

Vendor Rework

Engineering

Return Material

Other:

69736 .

When Completed Deliver To:

Name: TRVILLOAN / LAD WOODRUFF

Area: KTZ

Qty to Job: 1

Qty to Inv: 1

☒ Machine Shop

☐ Poly

☐ Weld

Qty Required: 1

Date Needed: _____

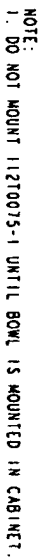
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Action Required: FOR PAINT

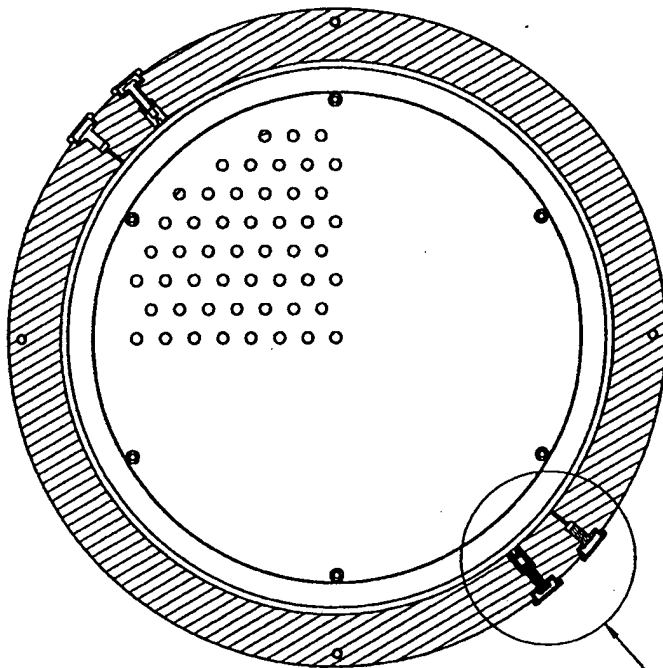
Reason: _____

EXHIBIT E



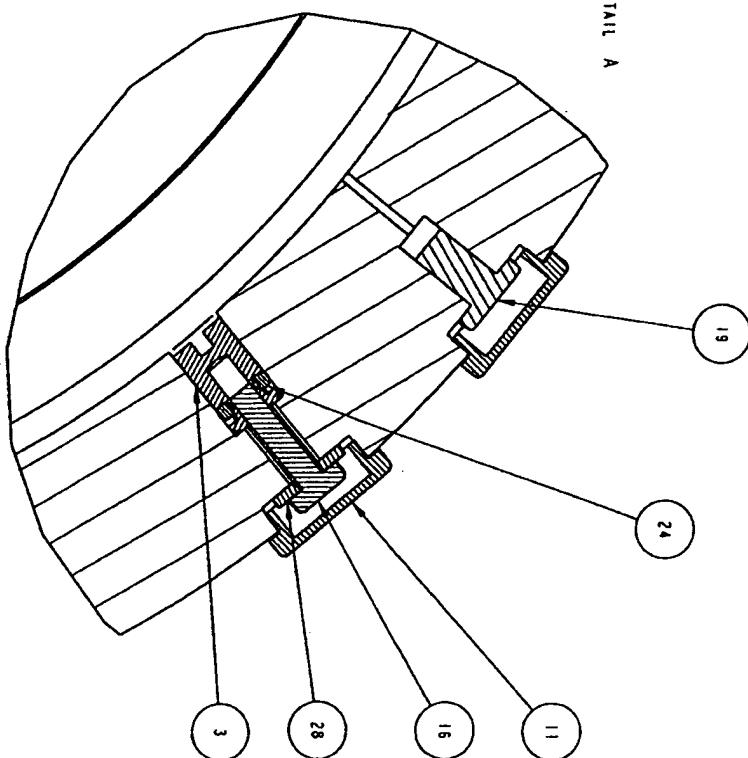
SCALE 0.250

[illegible]



SECTION C-C

SEE DETAIL A



DETAIL A
SCALE 2.000

SEMITOOL PROPRIETARY

Part No.	10010041-01
Rev.	B
Issue	1
Date	11/1/00
By	10010041
Check	3 of 3

EXHIBIT F

THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Daniel J. Woodruff, et al.

Application No.: 10/084,962

Confirmation No.: 2206

Filed: February 27, 2002

Title: ELECTROPLATING APPARATUS WITH
SEGMENTED ANODE ARRAY

Art Unit: 742

Examiner: Donald R. Valentine

Docket No.: 114183-7 (P98-0040US2)

**DECLARATION UNDER 37 C.F.R. § 1.131
OF DANIEL J. WOODRUFF AND KYLE M. HANSON**

We, Daniel J. Woodruff and Kyle M. Hanson, hereby declare and say
that:

We are the inventors of the subject matter disclosed and
claimed in the above-identified application, having made the invention described
therein in the United States. We conceived and reduced to practice the subject
matter of the claims in this application prior to April 21, 1998, the earliest filing
date claimed by U.S. Patent No. 6,261,433 ("the '433 patent").

2. To demonstrate such prior conception and reduction to practice,
we attach hereto as Exhibit A our Invention Disclosure for the concentric anode
array reactor and, as Exhibit B our Invention Record describing the anode

Application No. 10/084,962
Declaration Under 37 C.F.R. § 1.131
March 23, 2005

configuration, both forming the basis for the drawings contained in the above-identified application. Exhibit A, naming ourselves as inventors thereof, was prepared and signed by us well prior to April 21, 1998 and lists dates of conception and written description also prior to April 21, 1998. In addition, Exhibit A was witnessed and understood by two colleagues at Semitool, Inc., also prior to April 21, 1998.

3. Exhibit B which we both signed was also prepared prior to April 21, 1998 and witnessed before that same date. Together, Exhibits A and B were used in the preparation of the drawings contained in the present application, thus establishing conception of the method and apparatus disclosed in the above-identified application prior to April 21, 1998.

4. The segmented anode described in the present application is shown in Semitool engineering drawings, Exhibits C, D, E, F, G, H and I, just as described in the present application. The drawings of Exhibits C-I were each made prior to April 21, 1998 and were used to construct the segmented anode at the facility of Semitool, Inc. in Kalispell, Montana. That segmented anode was built, installed in a plating reactor as described in the present application and shown in Exhibits A and B, and that apparatus was successfully tested prior to April 21, 1998.

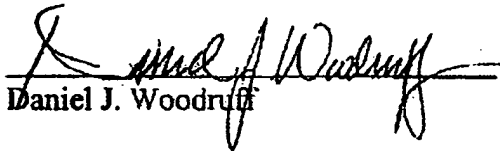
5. The dates contained on each of the exhibits have been removed, but all are prior to April 21, 1998, and thus corroborate conception and reduction to practice of the subject matter disclosed and claimed in the present application.

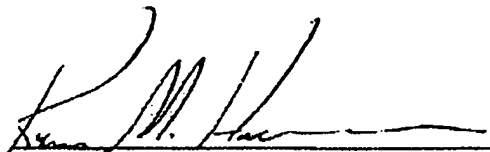
Application No. 10/084,962
Declaration Under 37 C.F.R. § 13
March 23, 2005

6. hereby declare under the penalty of perjury under the laws of the United States of America that the foregoing is true and correct to the best of my knowledge and belief.

7. Further declarants sayeth not.

Executed this 23rd day of March, 2005 in Kalispell, Montana.

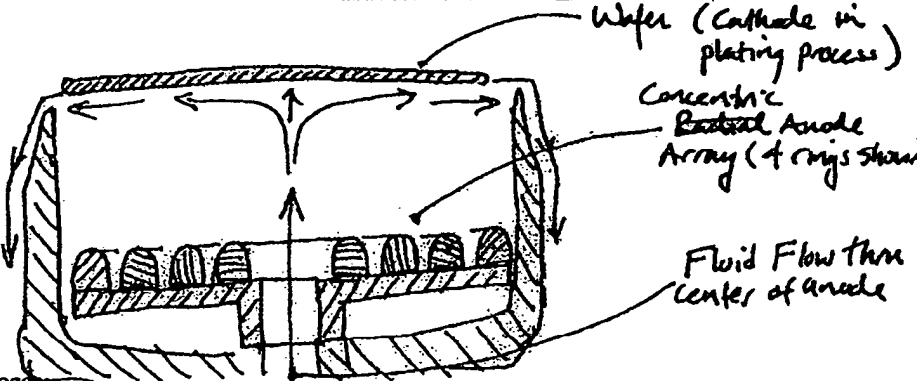

Daniel J. Woodruff


Kyle M. Hanson

INVENTION DISCLOSURE

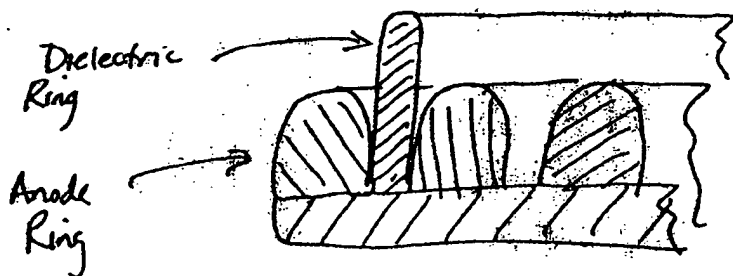
SEMITOOL, INC.

D. 0006

<p>Note: 1. Use Ink or Type Only 2. Do not erase errors. Line through any errors, initial and date. 3. Describe invention with drawings, sketches, etc. and a written explanation. Drawings may be below or attached. If attached, the inventor(s) and witnesses must sign and date each sheet. 4. Describe the advantages of this invention compared to the current approach, if any. 5. Inventor(s) and two (2) witnesses must sign and date each sheet. 6. Send original signed documents to the Intellectual Property Department. Retain a personal copy.</p>			
<p>Inventor(s) Name and Social Security Number</p> <p>Daniel J. Woodruff Kyle M. Hanson</p>			
<p>Title of Invention: TOOL: Plating</p> <p>Concentric Anode Array with Centered Fluid Flow</p>			
<p>Invention:</p> <p>Sketch</p> 			
<p>Explanation and Advantages:</p> <p>Plating fluid is pumped through the center of the anode array and impinges on the wafer surface. The plating rate on the wafer surface will vary radially across the due to the effect of the impinging fluid on the hydrodynamic boundary layer. This radial effect can be compensated for radially by operating the anode rings at different electrical potentials. (continued on attached sheet)</p>			
<p>Signature(s) of Inventor(s):</p> <p><i>[Signature of Daniel J. Woodruff]</i> <i>[Signature of Kyle M. Hanson]</i></p>		<p>Date:</p>	<p>Date of Conception:</p>
<p>Witnessed and Understood By:</p> <p><i>[Signature of Witness 1]</i> <i>[Signature of Witness 2]</i></p>		<p>Date:</p>	<p>Date of Written Description:</p>
<p>Working Model Prepared?</p> <p>Yes/No</p>		<p>Date:</p>	

Explanation and Advantages (Cont.)

In addition to affecting plating uniformity by using different anode potentials it would also be possible to affect uniformity with dielectric (insulating) material placed between the anode ring (see sketch)



The geometry of the dielectric material could be modified to provide the desired effect on plating. Tall geometries would tend to limit interaction of adjacent anodes (and perhaps collimate current flow to the wafer) while shorter or perforated geometries would tend to increase anode interaction. Similar effects may also be possible by positioning the anode rings at varying distances from the water surface. The advantages to this design are:

- 1) No diffuser is required between the anode and wafer. Fluid flow rate and current distribution can be controlled independent of one another in the proposed design, but can't in the existing system which uses a diffuser constructed of dielectric material. Having these variable independently controllable makes it easier to optimize the plating process.
- 2) Air bubbles introduced into the plating chamber by the incoming fluid flow are simply flushed passed the water surface and won't interfere with the plating process. With the existing system utilizing a diffuser these bubbles can attach to the diffuser surface and adversely impact diffuser performance.
- 3) Fluid flow through the center of the anode ensures the water surface will be wetted from the center out. This will prevent air being trapped at the center of the wafer when it first contacts the fluid surface.

☺

David Waduff
Kris Lee

INVENTION DISCLOSURE

D. -0005
B. 50

SEMITOOL, INC.

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Inventor(s) Name

KYLE M. HANSON
CHRIS K. HAUGAN

HENRY . STEVENS
DANIEL J. WOODRUFF

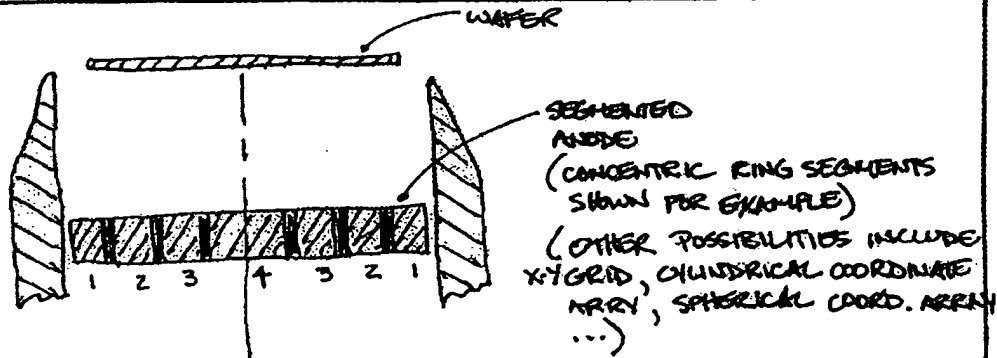
Tool or Process: ELECTRO CHEMICAL DEPOSITION

Title of Invention:

ANODE CONFIGURATION DYNAMIC CONTROL

Invention:

Sketch



Explanation and Advantages:

Then the use of a segmented anode structure and independent electrical control on each of these segments (definition of voltage or current flow), the capability to dynamically modify the anode configuration is enabled. This allows for optimization of the anode and therefore reactor current flow in order to compensate for the transient

Signature(s) of Inventor(s):	Date:	Date of Conception:	Date of First Sketch/Drawing:
Chris Haugan Henry Stevens Daniel J. Woodruff			
Witnessed and Understood By:	Date:	Date of Written Description:	Working Model Prepared?
Kyle M. Hanson Chris K. Haugan Henry Stevens			Yes <input type="radio"/> No <input checked="" type="radio"/>
			Date:

Explanation of Adu tags (cont)

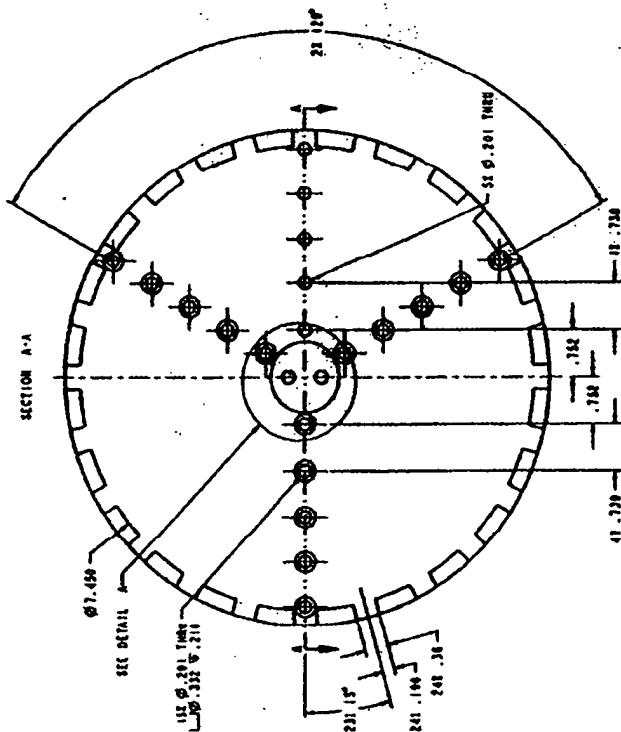
effects from the plated film growth on the wafer. As the film grows on the wafer the current distribution on the wafer will change due to the difference in the films electrical conductivity.

This capability to dynamically alter the anode configuration as the process progresses is becomes more important in the case of high resistance seed layers. In this case, the transient change in the film characteristics is made larger in magnitude as a layer of high electrical conductivity copper, for example, is deposited on a much lower conductivity layer.

That is, the plating is more sensitive to the local current density at the surface. For electrochemical plating, the potential applied to each anode segment will be individually controlled.

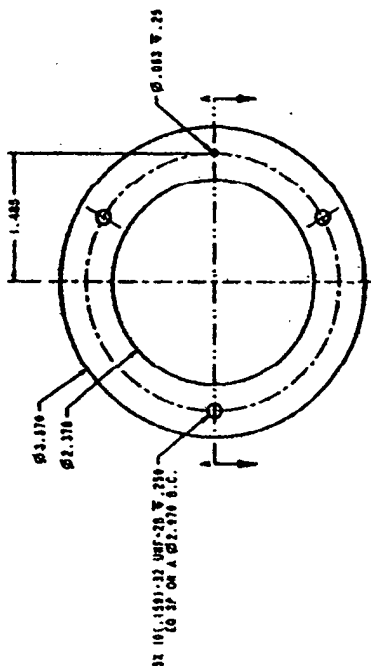
[Signature]

Chris Hays
 David W. Ruff
 Henry Stevens
 Kevin
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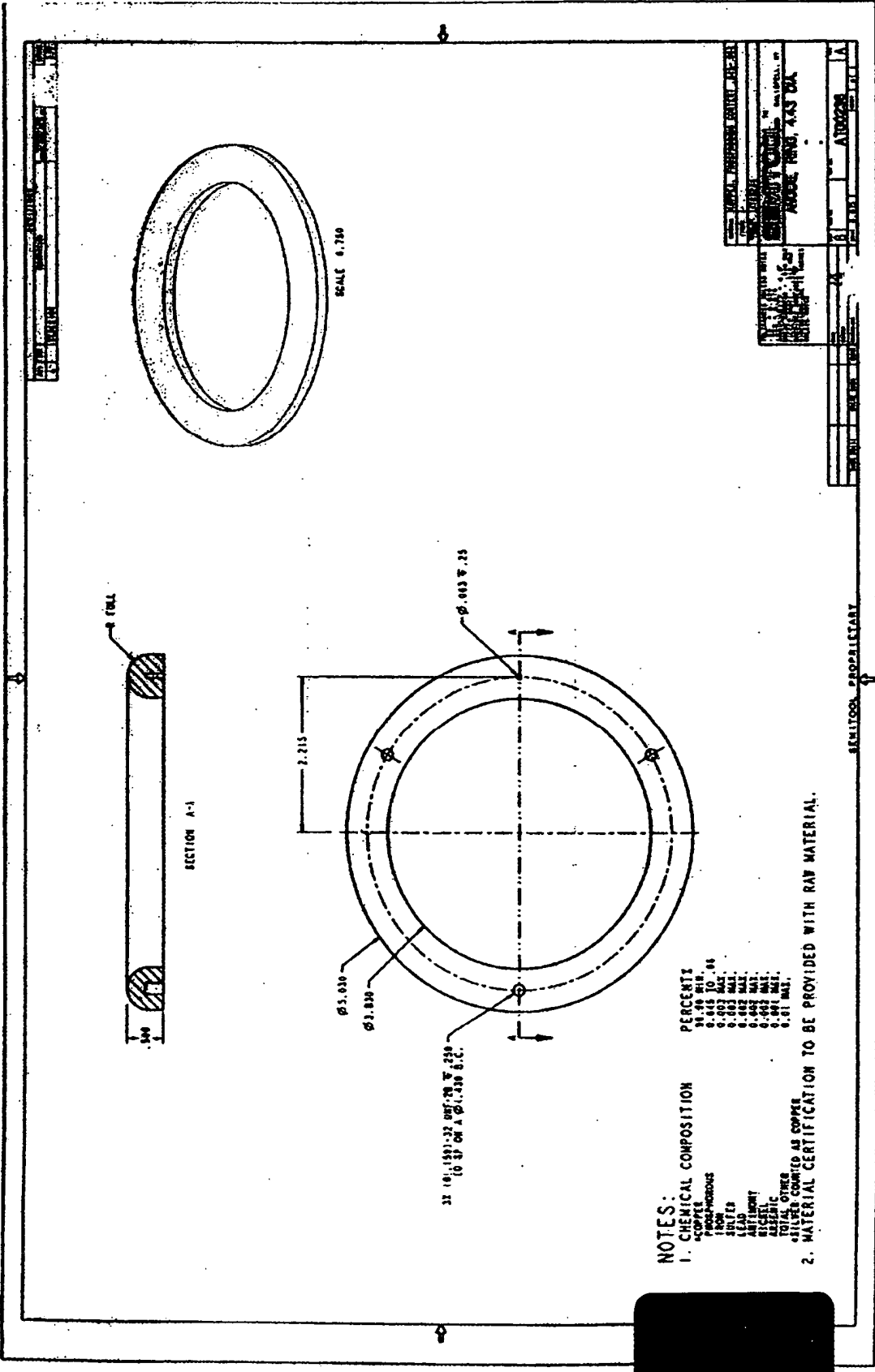
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NOTES:	PERCENT %
1. CHEMICAL COMPOSITION	
COPPER	99.98 MIN.
PHOSPHORUS	0.025 TO .04
IRON	0.003 MAX.
NICKEL	0.003 MAX.
LEAD	0.003 MAX.
ANTIMONY	0.002 MAX.
SILICON	0.002 MAX.
ARSENIC	0.001 MAX.
TOTAL OTHER	0.01 MAX.

2. MATERIAL CERTIFICATION TO BE PROVIDED WITH RAW MATERIAL.

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NOTES:

1. CHEMICAL COMPOSITION

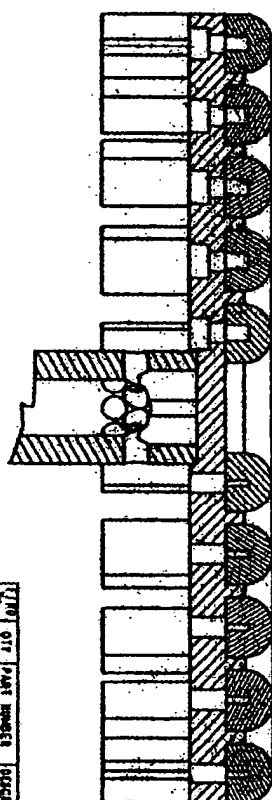
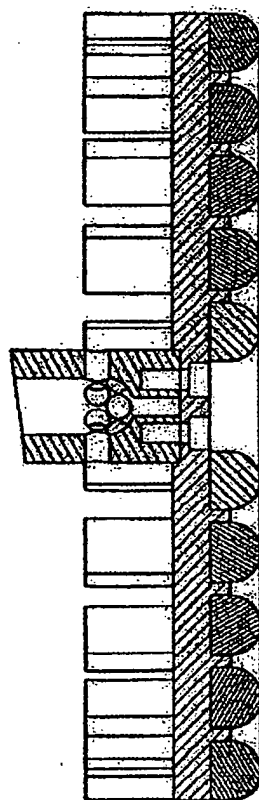
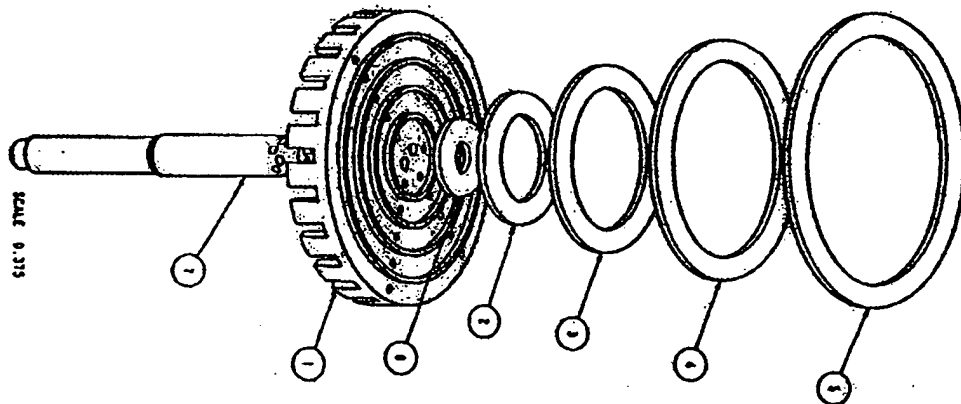
	PERCENTS
COPPER	95.70 MIN.
PHOSPHORUS	0.045 TO .06
IRON	0.003 MAX.
LEAD	0.003 MAX.
ANTIMONY	0.003 MAX.
ARSENIC	0.003 MAX.
OTHER	0.041 MAX.

ALL OTHERS AS SPECIFIED

2. MATERIAL CERTIFICATION TO BE PROVIDED WITH RAW MATERIAL.

THE UNITED STATES GOVERNMENT	
OFFICE OF THE SECRETARY OF THE ARMY	
WASHINGTON, D. C. 20315	
DATE: 1964 JAN 23	
BY: [Signature]	
TITLE: [Blank]	
PROJECT: [Blank]	
DRAWING NO.: [Blank]	
SHEET NO.: [Blank]	
TOTAL SHEETS: [Blank]	

SEMITON PROPRIETARY



SECTION C-C

SECTION B-B

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